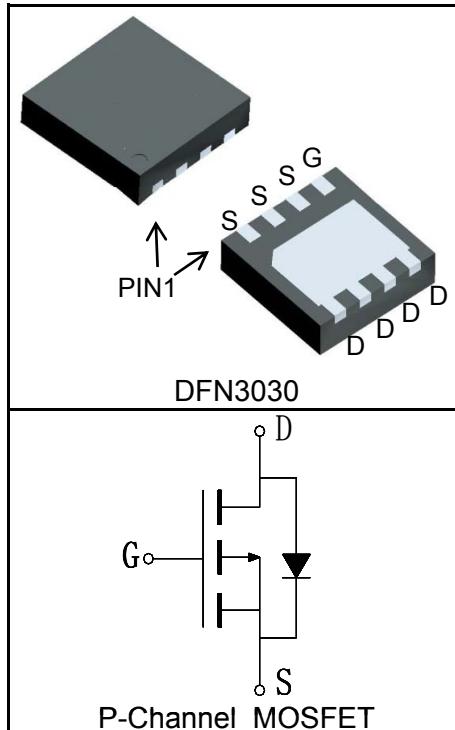


Features

- -30V/-30A,
- $R_{DS(ON)} = 10\text{m}\Omega$ (Typ.)@ $V_{GS}=-10\text{V}$
- $R_{DS(ON)} = 18\text{m}\Omega$ (Typ.)@ $V_{GS}=-4.5\text{V}$
- Reliable and Rugged
- 100% avalanche tested
- Lead Free and Green Devices Available (RoHS Compliant)

Pin Description



Applications

- Switching Application Systems
- On Board power for server
- Synchronous rectification

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
Common Ratings ($T_c=25^\circ\text{C}$ Unless Otherwise Noted)			
V_{DSS}	Drain-Source Voltage	-30	V
V_{GSS}	Gate-Source Voltage	± 20	
T_J	Maximum Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
I_S	Diode Continuous Forward Current	$T_c=25^\circ\text{C}$	-30
Mounted on Large Heat Sink			
$I_{DP}^{①}$	300 μs Pulse Drain Current Tested	$T_c=25^\circ\text{C}$	-96
$I_D^{②}$	Continuous Drain Current@ $T_c(V_{GS}=-10\text{V})$	$T_c=25^\circ\text{C}$	-30
		$T_c=100^\circ\text{C}$	-19
P_D	Maximum Power Dissipation@ $T_c(V_{GS}=-10\text{V})^{③}$	$T_A=25^\circ\text{C}$	-9.3
		$T_A=70^\circ\text{C}$	-7.5
	Maximum Power Dissipation@ T_c	$T_c=25^\circ\text{C}$	33
		$T_c=100^\circ\text{C}$	13
	Maximum Power Dissipation@ T_A	$T_A=25^\circ\text{C}$	3.5
		$T_A=70^\circ\text{C}$	2.3